



**SDI Review Form 1.6**

Journal Name:	<a href="#">Physical Science International Journal</a>
Manuscript Number:	2015_PSIJ_18553
Title of the Manuscript:	Electrical and photoelectric properties of crystal InGaTe2
Type of the Article	

**General guideline for Peer Review process:**

This journal's peer review policy states that **NO** manuscript should be rejected only on the basis of '**lack of Novelty**', provided the manuscript is scientifically robust and technically sound.

To know the complete guideline for Peer Review process, reviewers are requested to visit this link:

(<http://www.sciencedomain.org/page.php?id=sdi-general-editorial-policy#Peer-Review-Guideline>)



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**PART 1: Review Comments**

	<b>Reviewer's comment</b>	<b>Author's comment</b> (if agreed with reviewer, correct the manuscript and highlight that part in the manuscript. It is mandatory that authors should write his/her feedback here)
<b><u>Compulsory</u></b> REVISION comments	<p>Recommendation: Accept after minor revision.</p> <p>Additional comments: The target of the manuscript is the study of electrical and photo-conductivity of semiconductors of AIIIBIIIC2VI system. So, that the manuscript is dedicated to an actual problem of semiconductor physics. However, this paper can be recommended for publication in the PSIJ after minor revision because of some problems in the manuscript. They are as follows:</p> <p>There are a lot of technical errors in the text. Some of these errors were marked by yellow.</p>	
<b><u>Minor</u></b> REVISION comments		
<b><u>Optional/General</u></b> comments		

**Reviewer Details:**

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